

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







preliminary

$$V_{RRM} = 100V$$

$$I_{FAV} = 2x \quad 15A$$

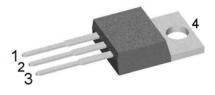
$$V_F = 0.73V$$

High Performance Schottky Diode Low Loss and Soft Recovery Common Cathode

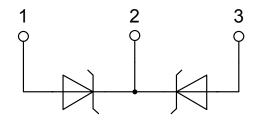
Schottky Diode Gen<sup>2</sup>

Part number

DSA30C100PB



Backside: cathode



### Features / Advantages:

- Very low Vf
- Extremely low switching losses
- Low Irm values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

### Applications:

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

### Package: TO-220

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0





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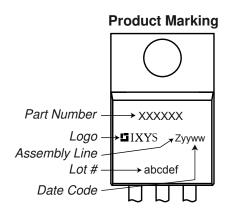
Schottky					Ratings		
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V <sub>RSM</sub>	max. non-repetitive reverse block	ing voltage	$T_{VJ} = 25^{\circ}C$			100	V
V <sub>RRM</sub>	max. repetitive reverse blocking v	oltage	$T_{VJ} = 25^{\circ}C$			100	V
I <sub>R</sub>	reverse current, drain current	V <sub>R</sub> = 100 V	$T_{VJ} = 25^{\circ}C$			250	μΑ
		$V_R = 100 V$	$T_{VJ} = 125^{\circ}C$			2.5	mΑ
V <sub>F</sub>	forward voltage drop	I <sub>F</sub> = 15 A	$T_{VJ} = 25^{\circ}C$			0.91	٧
		$I_F = 30 \text{ A}$				1.08	V
		I <sub>F</sub> = 15 A	T <sub>VJ</sub> = 125°C			0.73	V
		$I_F = 30 \text{ A}$				0.91	٧
I <sub>FAV</sub>	average forward current	T <sub>c</sub> = 155°C	T <sub>vJ</sub> = 175°C			15	Α
		rectangular d = 0.5					i 
V <sub>F0</sub>	threshold voltage		T <sub>vJ</sub> = 175°C			0.46	V
r <sub>F</sub>	slope resistance } for power lo	oss calculation only				12.4	mΩ
R <sub>thJC</sub>	thermal resistance junction to cas	e				1.75	K/W
R <sub>thCH</sub>	thermal resistance case to heatsing	nk			0.50		K/W
P <sub>tot</sub>	total power dissipation		$T_C = 25^{\circ}C$			35	W
I <sub>FSM</sub>	max. forward surge current	$t = 10 \text{ ms}$ ; (50 Hz), sine; $V_R = 0 \text{ V}$	$T_{VJ} = 45^{\circ}C$			340	Α
C	junction capacitance	V <sub>R</sub> = 12 V f = 1 MHz	T <sub>VJ</sub> = 25°C		146		pF



## DSA30C100PB

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Package TO-220				Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit	
I <sub>RMS</sub>	RMS current	per terminal 1)			35	Α	
T <sub>VJ</sub>	virtual junction temperature		-55	1	175	°C	
T <sub>op</sub>	operation temperature		-55	i	150	°C	
T <sub>stg</sub>	storage temperature		-55	i	150	°C	
Weight				2		g	
M <sub>D</sub>	mounting torque		0.4		0.6	Nm	
F <sub>c</sub>	mounting force with clip		20	)	60	N	



#### Part number

D = Diode

S = Schottky Diode

A = low VF

30 = Current Rating [A]

C = Common Cathode

100 = Reverse Voltage [V] PB = TO-220AB (3)

Ordering	Part Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSA30C100PB	DSA30C100PB	Tube	50	503515

Similar Part	Package	Voltage class
DSA30C100PN	TO-220ABFP (3)	100
DSA30C100HB	TO-247AD (3)	100
DSA30C100QB	TO-3P (3)	100

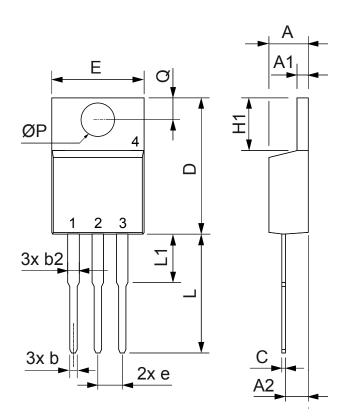
Equiva	alent Circuits for	Simulation	* on die level	T <sub>VJ</sub> = 175 °C
$I \rightarrow V_0$	R <sub>o</sub> -	Schottky		
V <sub>0 max</sub>	threshold voltage	0.46		V
R <sub>0 max</sub>	slope resistance *	9.2		$m\Omega$



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### Outlines TO-220



Dim.	Millimeter		Inches		
	Min.	Max.	Min.	Max.	
Α	4.32	4.82	0.170	0.190	
A1	1.14	1.39	0.045	0.055	
A2	2.29	2.79	0.090	0.110	
b	0.64	1.01	0.025	0.040	
b2	1.15	1.65	0.045	0.065	
С	0.35	0.56	0.014	0.022	
D	14.73	16.00	0.580	0.630	
Е	9.91	10.66	0.390	0.420	
е	2.54	BSC	0.100	BSC	
H1	5.85	6.85	0.230	0.270	
L	12.70	13.97	0.500	0.550	
L1	2.79	5.84	0.110	0.230	
ØP	3.54	4.08	0.139	0.161	
Q	2.54	3.18	0.100	0.125	

